CMOS Digital Integrated Circuits Silicon Monolithic

74HC125D,74HC126D

1. Functional Description

・ Quad Bus Buffer, Non-Inverted 3-State Outputs

74HC125D: Quad Bus Buffer

74HC126D: Quad Bus Buffer

2. General

The 74HC125D,74HC126D are high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The 74HC125D requires the 3-state control input $\overline{G}$ to be set high to place the output into the high impedance state, whereas the 74HC126D requires the control input to be set low to place the output into high impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

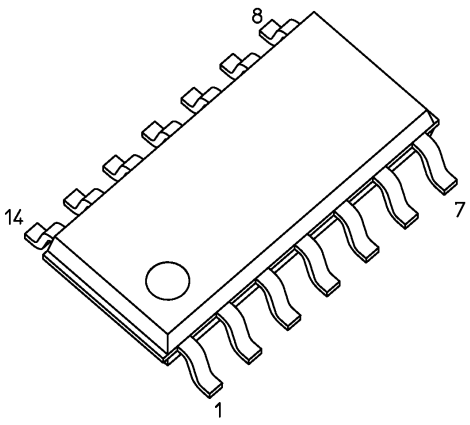
(1) High speed: t_{pd} = 10 ns (typ.) at V_{CC} = 6.0 V

(2) Low power dissipation: I_{CC} = 4.0 μA (max) at T_a = 25 °C

(3) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$

(4) Wide operating voltage range: $V_{CC(opr)}$ = 2.0 to 6.0 V

4. Packaging



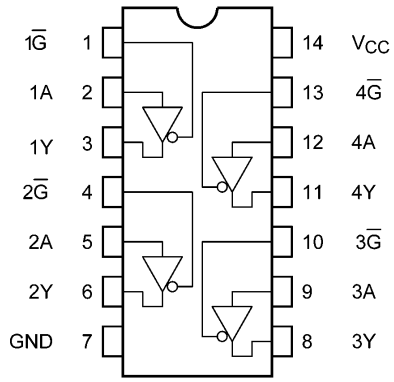
SOIC14

Start of commercial production

2016-02

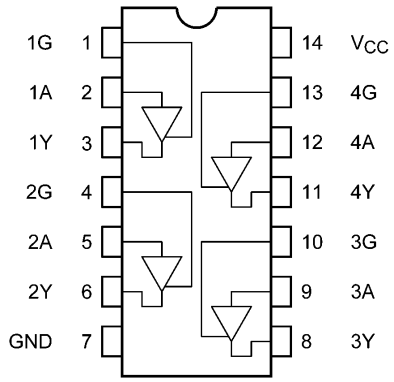
5. Pin Assignment

74HC125D



(top view)

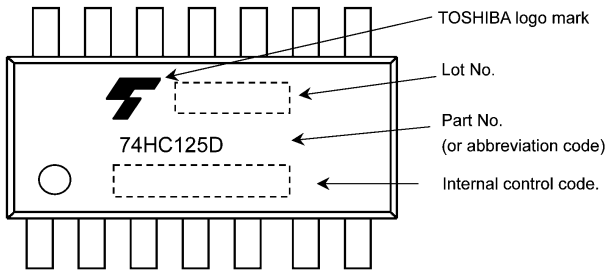
74HC126D



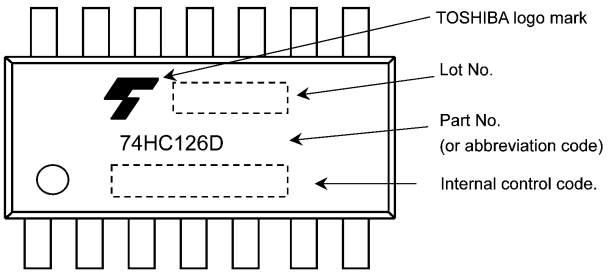
(top view)

6. Marking

74HC125D

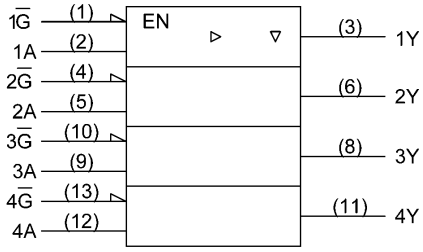


74HC126D

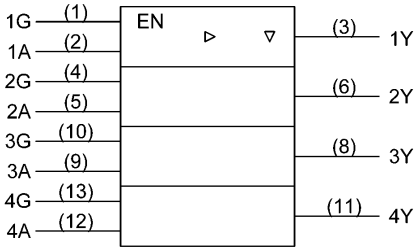


7. IEC Logic Symbol

74HC125D



74HC126D



8. Truth Table

Input $\overline{G}$ (74HC125D)	Input G (74HC126D)	Input A	Output Y
H	L	X	Z
L	H	L	L
L	H	H	H

X: Don't care
Z: High impedance

9. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to V_{CC} + 0.5	V
Output voltage	V_{OUT}		-0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}		±20	mA
Output diode current	I_{OK}		±20	mA
Output current	I_{OUT}		±35	mA
V_{CC}/ground current	I_{CC}		±75	mA
Power dissipation	P_D	(Note 1)	500	mW
Storage temperature	T_{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

10. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V_{CC}	—	2.0 to 6.0	V
Input voltage	V_{IN}	—	0 to V_{CC}	V
Output voltage	V_{OUT}	—	0 to V_{CC}	V
Operating temperature	T_{opr}	—	-40 to 125	°C
Input rise and fall times	t_r,t_f	—	0 to 50	μs

Note: The operating ranges must be maintained to ensure the normal operation of the device.
Unused inputs must be tied to either V_{CC} or GND.

11. Electrical Characteristics

11.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Typ.	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	V
				4.5	3.15	—	—	
				6.0	4.20	—	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	V
				4.5	—	—	1.35	
				6.0	—	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -20 μA	2.0	1.9	2.0	—	V
				4.5	4.4	4.5	—	
				6.0	5.9	6.0	—	
			I_{OH} = -6 mA	4.5	4.18	4.31	—	
			I_{OH} = -7.8 mA	6.0	5.68	5.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20 μA	2.0	—	0.0	0.1	V
				4.5	—	0.0	0.1	
				6.0	—	0.0	0.1	
			I_{OL} = 6 mA	4.5	—	0.17	0.26	
			I_{OL} = 7.8 mA	6.0	—	0.18	0.26	
3-state output OFF-state leakage current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		6.0	—	—	±0.5	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	—	—	±0.1	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	—	—	4.0	μA

11.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	V
				4.5	3.15	—	
				6.0	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	0.50	V
				4.5	—	1.35	
				6.0	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -20 μA	2.0	1.9	—	V
				4.5	4.4	—	
				6.0	5.9	—	
			I_{OH} = -6 mA	4.5	4.13	—	
			I_{OH} = -7.8 mA	6.0	5.63	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20 μA	2.0	—	0.1	V
				4.5	—	0.1	
				6.0	—	0.1	
			I_{OL} = 6 mA	4.5	—	0.33	
			I_{OL} = 7.8 mA	6.0	—	0.33	
3-state output OFF-state leakage current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		6.0	—	±5.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	—	40.0	μA

11.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	V
				4.5	3.15	—	
				6.0	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	0.50	V
				4.5	—	1.35	
				6.0	—	1.80	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = -20 μA	2.0	1.9	—	V
				4.5	4.4	—	
				6.0	5.9	—	
			I_{OH} = -6 mA	4.5	3.7	—	
			I_{OH} = -7.8 mA	6.0	5.2	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 20 μA	2.0	—	0.1	V
				4.5	—	0.1	
				6.0	—	0.1	
			I_{OL} = 6 mA	4.5	—	0.4	
			I_{OL} = 7.8 mA	6.0	—	0.4	
3-state output OFF-state leakage current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		6.0	—	±10.0	μA
Input leakage current	I_{IN}	V_{IN} = V_{CC} or GND		6.0	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		6.0	—	160.0	μA

11.4. AC Characteristics (Unless otherwise specified, T_a = 25 °C, Input: t_r = t_f = 6 ns)

Characteristics	Symbol	Note	Test Condition	C_L (pF)	V_{CC} (V)	Min	Typ.	Max	Unit
Output transition time	t_{TLH},t_{THL}		—	50	2.0	—	20	60	ns
					4.5	—	6	12	
					6.0	—	5	10	
Propagation delay time	t_{PLH},t_{PHL}		—	50	2.0	—	30	90	ns
					4.5	—	11	18	
					6.0	—	10	15	
				150	2.0	—	42	130	
					4.5	—	14	26	
					6.0	—	12	22	
Output enable time	t_{PZL},t_{PZH}		R_L = 1 kΩ	50	2.0	—	30	90	ns
					4.5	—	11	18	
					6.0	—	10	15	
				150	2.0	—	42	130	
					4.5	—	14	26	
					6.0	—	12	22	
Output disable time	t_{PLZ},t_{PHZ}		R_L = 1 kΩ	50	2.0	—	24	100	ns
					4.5	—	12	20	
					6.0	—	10	17	
Input capacitance	C_{IN}		—			—	5	10	pF
Output capacitance	C_{OUT}		—			—	3	—	pF
Power dissipation capacitance	C_{PD}	(Note 1)	—			—	23	—	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per gate)

11.5. AC Characteristics
(Unless otherwise specified, T_a = -40 to 85 °C, Input: $t_r = t_f$ = 6 ns)

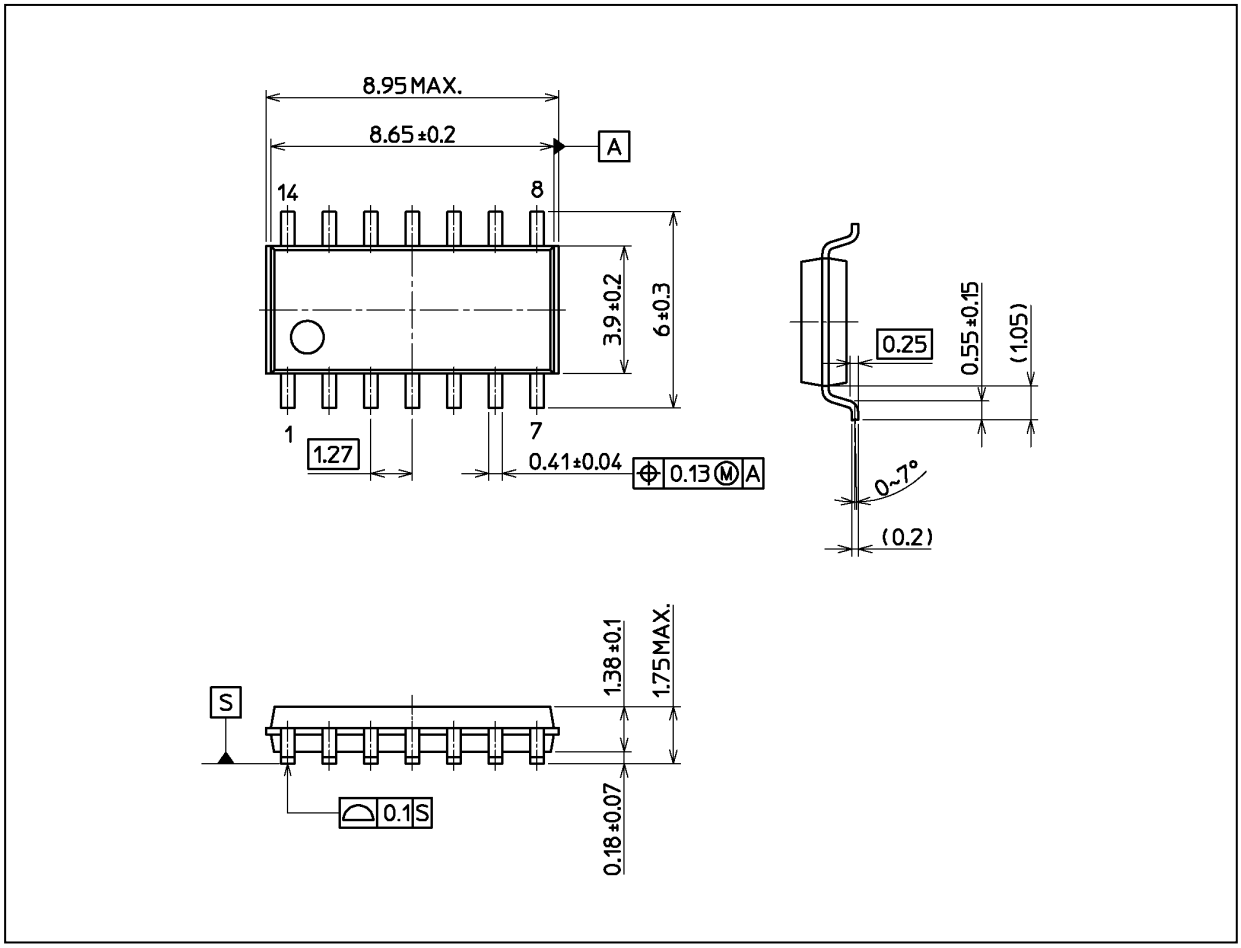
Characteristics	Symbol	Test Condition	C_L (pF)	V_{CC} (V)	Min	Max	Unit
Output transition time	t_{TLH},t_{THL}	—	50	2.0	—	75	ns
				4.5	—	15	
				6.0	—	13	
Propagation delay time	t_{PLH},t_{PHL}	—	50	2.0	—	115	ns
				4.5	—	23	
				6.0	—	20	
			150	2.0	—	165	
				4.5	—	33	
				6.0	—	28	
Output enable time	t_{PZL},t_{PZH}	R_L = 1 kΩ	50	2.0	—	115	ns
				4.5	—	23	
				6.0	—	20	
			150	2.0	—	165	
				4.5	—	33	
				6.0	—	28	
Output disable time	t_{PLZ},t_{PHZ}	R_L = 1 kΩ	50	2.0	—	125	ns
				4.5	—	25	
				6.0	—	21	
Input capacitance	C_{IN}	—			—	10	pF

11.6. AC Characteristics
(Unless otherwise specified, T_a = -40 to 125 °C, Input: $t_r = t_f$ = 6 ns)

Characteristics	Symbol	Test Condition	C_L (pF)	V_{CC} (V)	Min	Max	Unit
Output transition time	t_{TLH},t_{THL}	—	50	2.0	—	90	ns
				4.5	—	18	
				6.0	—	15	
Propagation delay time	t_{PLH},t_{PHL}	—	50	2.0	—	150	ns
				4.5	—	30	
				6.0	—	26	
			150	2.0	—	195	
				4.5	—	39	
				6.0	—	33	
Output enable time	t_{PZL},t_{PZH}	R_L = 1 kΩ	50	2.0	—	190	ns
				4.5	—	38	
				6.0	—	32	
			150	2.0	—	195	
				4.5	—	39	
				6.0	—	33	
Output disable time	t_{PLZ},t_{PHZ}	R_L = 1 kΩ	50	2.0	—	190	ns
				4.5	—	38	
				6.0	—	32	

Package Dimensions

Unit: mm



Weight: 0.13 g (typ.)

Package Name(s)
Nickname: SOIC14

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